

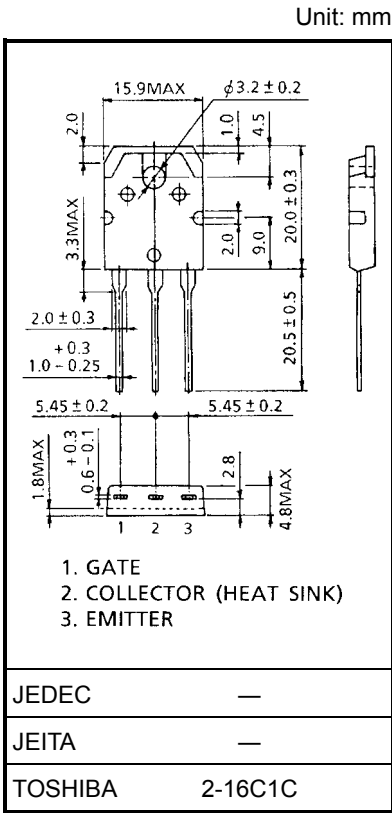
GT10Q301

High Power Switching Applications
Motor Control Applications

- The 3rd generation
- Enhancement-mode
- High speed: $t_f = 0.32 \mu s$ (max)
- Low saturation voltage: $V_{CE(sat)} = 2.7 V$ (max)
- FRD included between emitter and collector

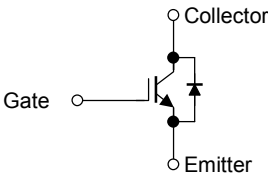
Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-emitter voltage		V_{CES}	1200	V
Gate-emitter voltage		V_{GES}	± 20	V
Collector current	DC	I_C	10	A
	1 ms	I_{CP}	20	
Emitter-collector forward current	DC	I_F	10	A
	1 ms	I_{FM}	20	
Collector power dissipation (Tc = 25°C)		P_C	140	W
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	-55 to 150	°C



Weight: 4.6 g (typ.)

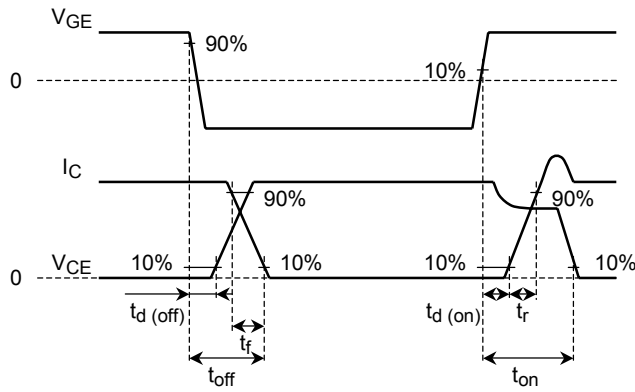
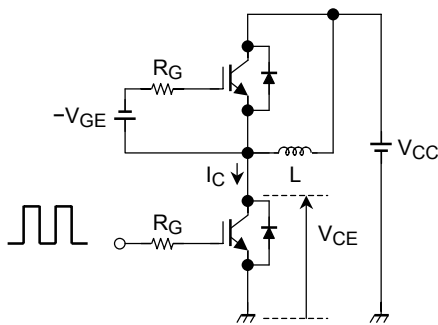
Equivalent Circuit

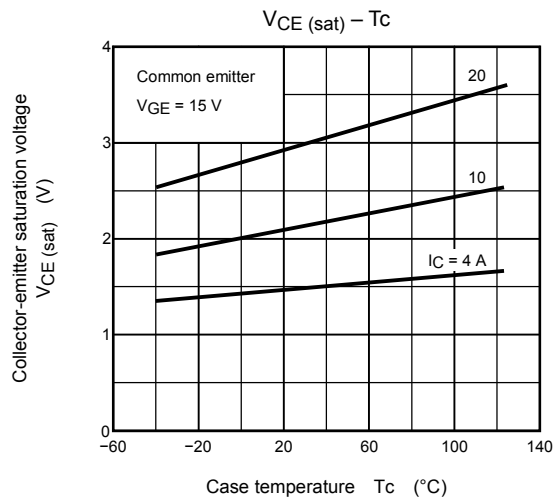
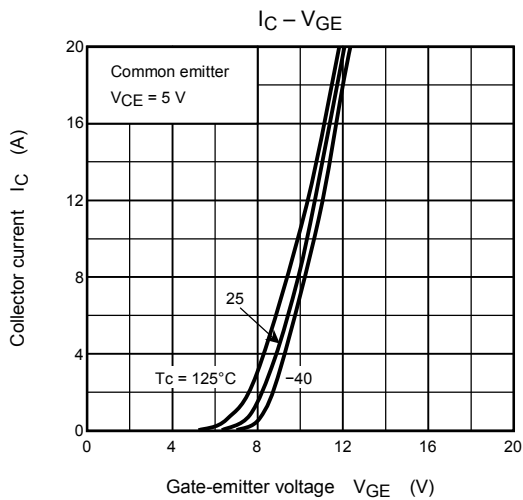
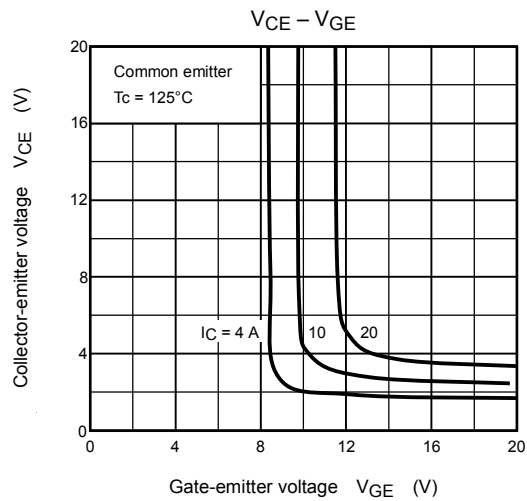
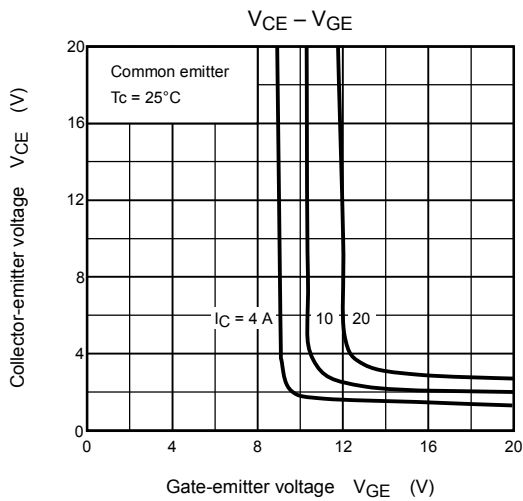
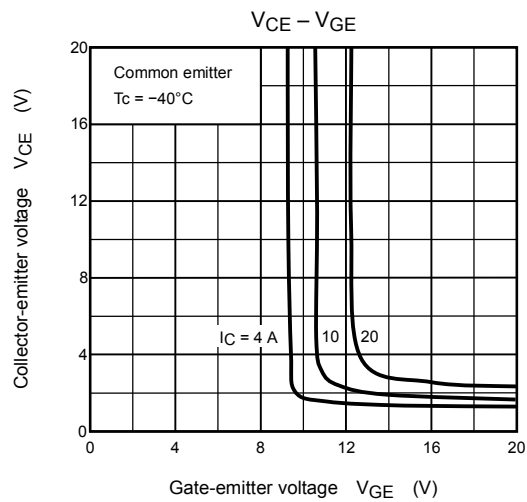
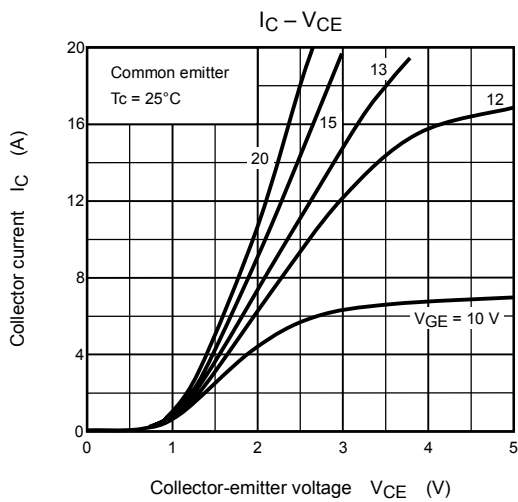


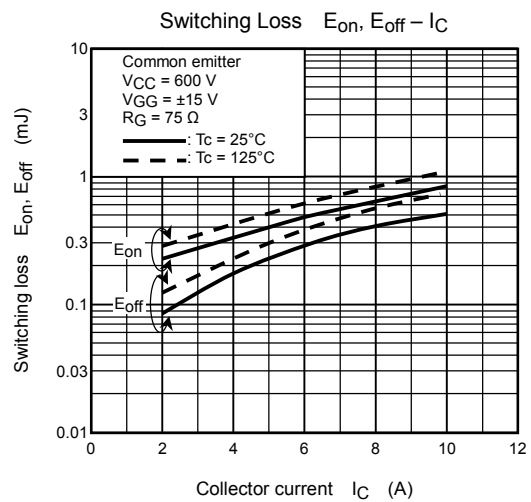
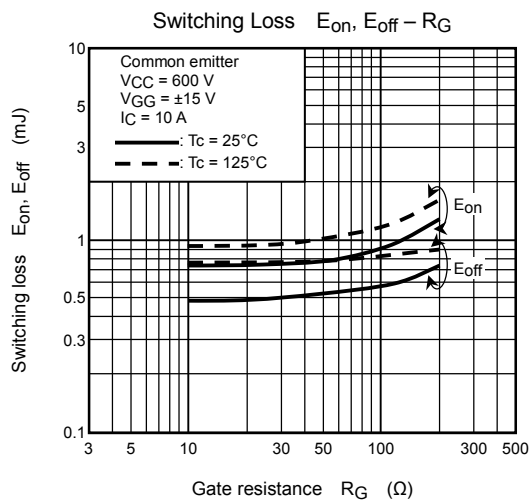
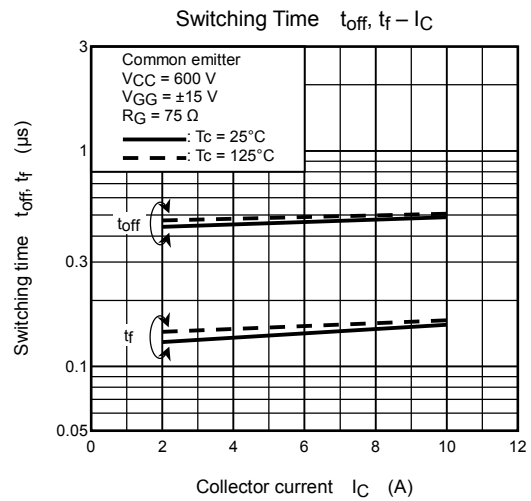
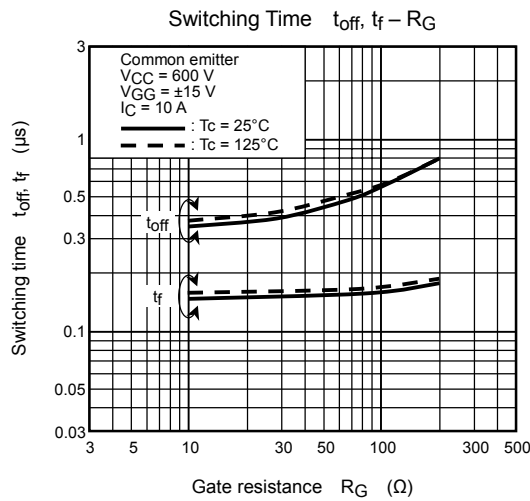
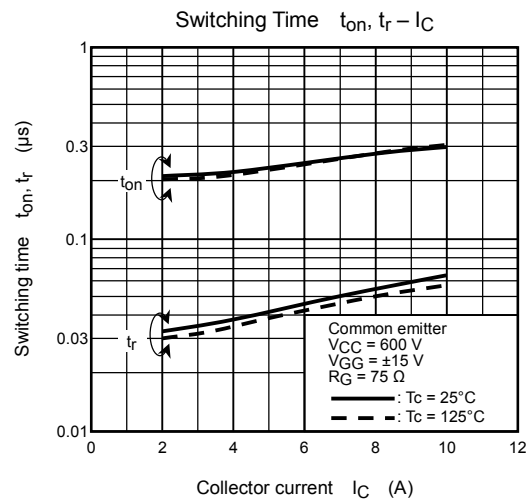
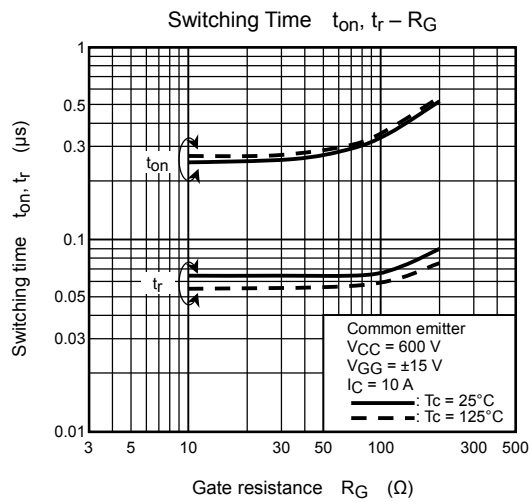
Electrical Characteristics (Ta = 25°C)

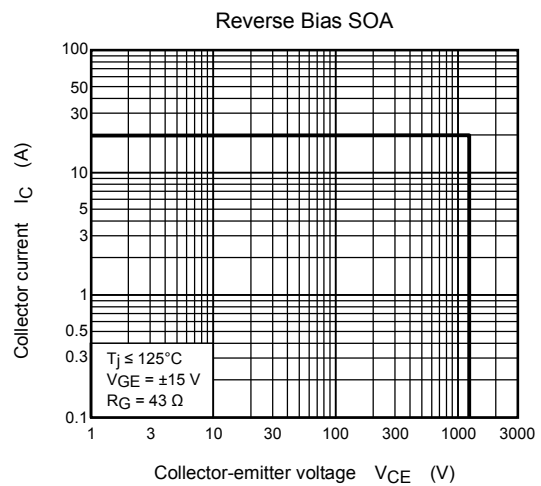
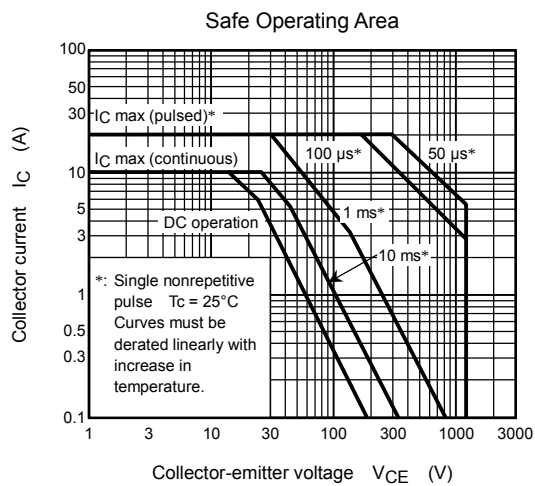
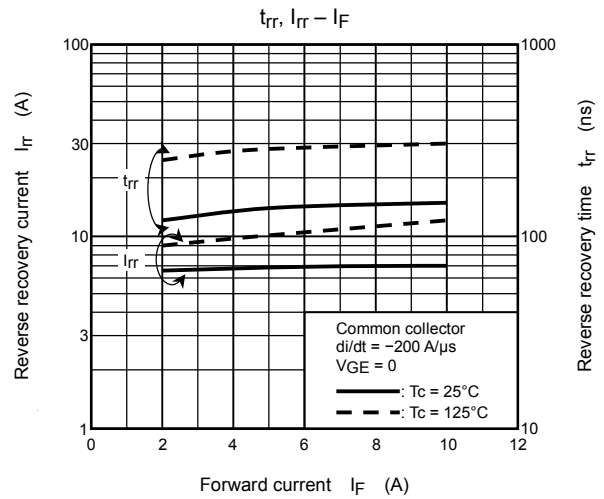
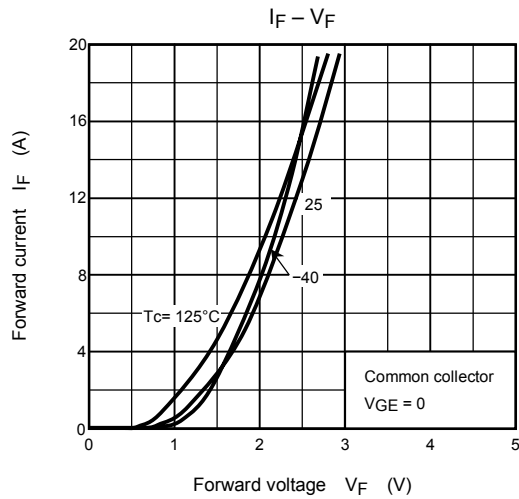
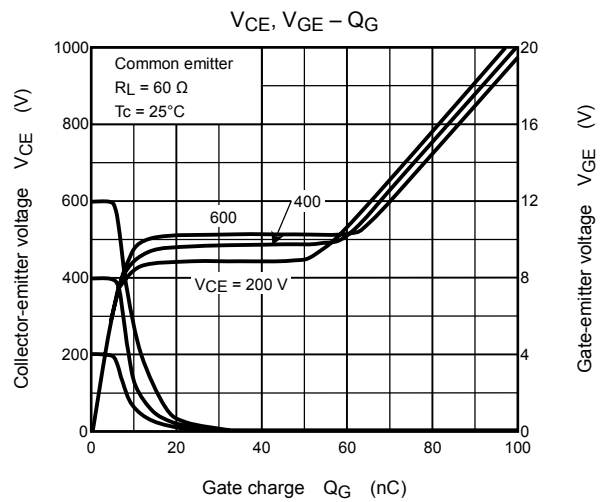
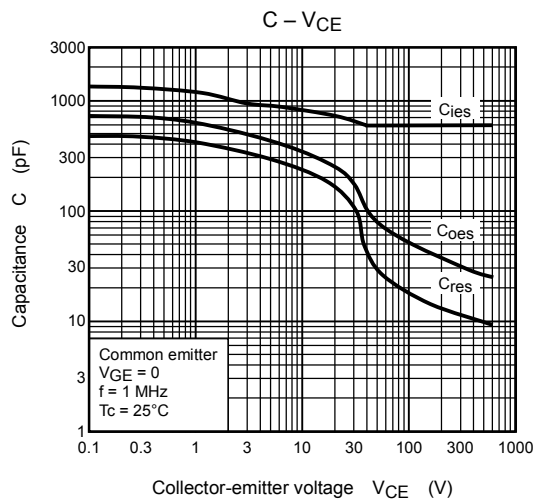
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GES}	$V_{GE} = \pm 20 \text{ V}, V_{CE} = 0$	—	—	± 500	nA
Collector cut-off current		I_{CES}	$V_{CE} = 1200 \text{ V}, V_{GE} = 0$	—	—	1.0	mA
Gate-emitter cut-off voltage		$V_{GE} \text{ (OFF)}$	$I_C = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	4.0	—	7.0	V
Collector-emitter saturation voltage		$V_{CE} \text{ (sat)}$	$I_C = 10 \text{ A}, V_{GE} = 15 \text{ V}$	—	2.1	2.7	V
Input capacitance		C_{ies}	$V_{CE} = 50 \text{ V}, V_{GE} = 0, f = 1 \text{ MHz}$	—	600	—	pF
Switching time	Rise time	t_r	Inductive load $V_{CC} = 600 \text{ V}, I_C = 10 \text{ A}$ $V_{GG} = \pm 15 \text{ V}, R_G = 75 \Omega$ (Note)	—	0.07	—	μs
	Turn-on time	t_{on}		—	0.30	—	
	Fall time	t_f		—	0.16	0.32	
	Turn-off time	t_{off}		—	0.50	—	
Peak forward voltage		V_F	$I_F = 10 \text{ A}, V_{GE} = 0$	—	—	3.0	V
Reverse recovery time		t_{rr}	$I_F = 10 \text{ A}, di/dt = -200 \text{ A}/\mu\text{s}$	—	—	350	ns
Thermal resistance (IGBT)		$R_{th} \text{ (j-c)}$	—	—	—	0.89	$^{\circ}\text{C}/\text{W}$
Thermal resistance (diode)		$R_{th} \text{ (j-c)}$	—	—	—	1.79	$^{\circ}\text{C}/\text{W}$

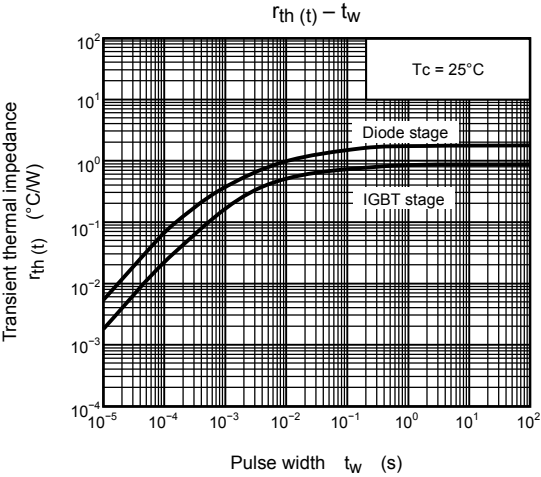
Note: Switching time measurement circuit and input/output waveforms











RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.